

BAT54W series

Schottky barrier diodes

Rev. 3 — 20 November 2012

Product data sheet

1. Product profile

1.1 General description

Planar Schottky barrier diodes with an integrated guard ring for stress protection, encapsulated in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Low forward voltage
- Low capacitance
- AEC-Q101 qualified

1.3 Applications

- Ultra high-speed switching
- Line termination

- Voltage clamping
- Reverse polarity protection

1.4 Quick reference data

Table 1. Quick reference data $T_{amb} = 25 \, ^{\circ}\text{C}$ unless otherwise specified.

unio -	<u> </u>					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
V_R	reverse voltage		-	-	30	V
V_{F}	forward voltage	$I_F = 100 \text{ mA}$	<u>[1]</u> _	-	800	mV
I _R	reverse current	$V_{R} = 25 \text{ V}$	<u>[1]</u> _	-	2	μΑ

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

2. Pinning information

Table 2. Pinning

Pin Description Simplified outline Graphic symbol

BAT54W

1 anode
2 not connected
3 cathode



 Table 2.
 Pinning ...continued

Pin	Description	Simplified outline	Graphic symbol
BAT54AW			
1	cathode (diode 1)		
2	cathode (diode 2)	3	3
3	common anode	1 2	1
BAT54CW			
1	anode (diode 1)		0
2	anode (diode 2)	3	3
3	common cathode	1 2	1 2 2
BAT54SW			
1	anode (diode 1)		_
2	cathode (diode 2)	3	3
3	cathode (diode 1), anode (diode 2)	1 2	1 2 006aaa437

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BAT54W series	SC-70	plastic surface-mounted package; 3 leads	SOT323

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BAT54W	L4*
BAT54AW	42*
BAT54CW	43*
BAT54SW	44*

[1] * = placeholder for manufacturing site code.

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode					
V _R	reverse voltage		-	30	V
I _F	forward current		-	200	mA
I _{FRM}	repetitive peak forward current	$t_p \leq 1 \text{ s; } \delta \leq 0.5$		300	mA
I _{FSM}	non-repetitive peak forward current	square wave; t _p < 10 ms	<u>[1]</u> _	600	mA
Per device;	one diode loaded				
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[2]	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] $T_j = 25$ °C before surge.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device;	one diode loaded					
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

7. Characteristics

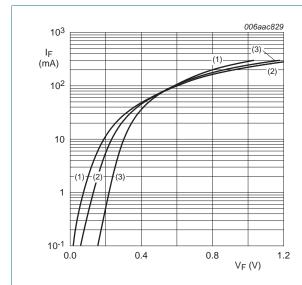
Table 7. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diod	е					
V_{F}	forward voltage		<u>[1]</u>			
		$I_F = 0.1 \text{ mA}$	-	-	240	mV
		$I_F = 1 \text{ mA}$	-	-	320	mV
		I _F = 10 mA	-	-	400	mV
	I _F = 30 mA	-	-	500	mV	
		I _F = 100 mA	-	-	800	mV
I_R	reverse current	V _R = 25 V	<u>[1]</u> -	-	2	μΑ
C_{d}	diode capacitance	$f = 1 MHz; V_R = 1 V$	-	-	10	pF
t _{rr}	reverse recovery time		[2] _	-	5	ns

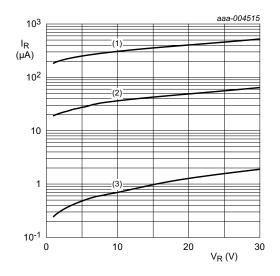
^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

^[2] When switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA.



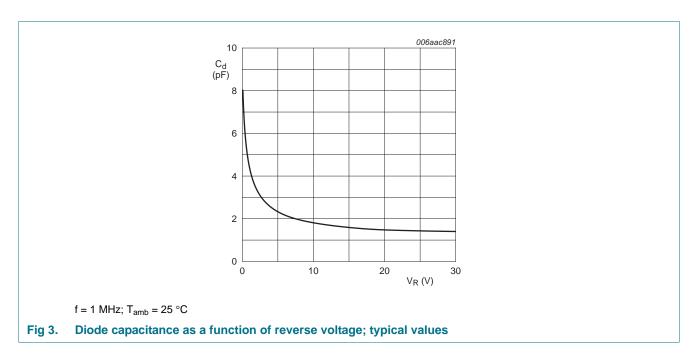
- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values

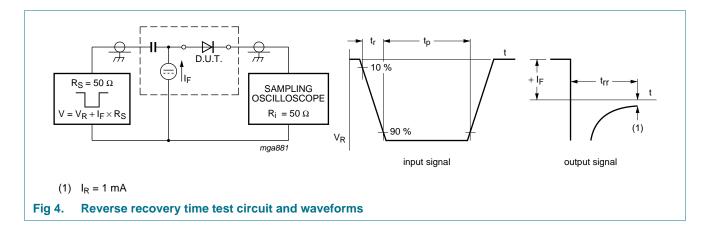


- (1) $T_{amb} = 125 \, ^{\circ}C$
- (2) $T_{amb} = 85 \, ^{\circ}C$
- (3) $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values



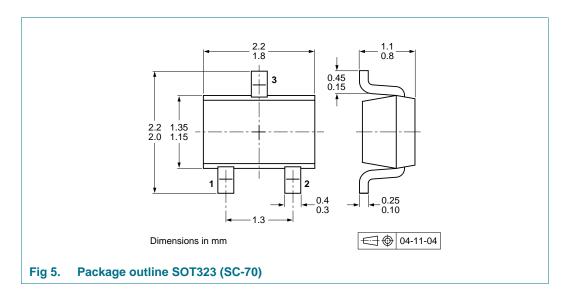
8. Test information



8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline



10. Packing information

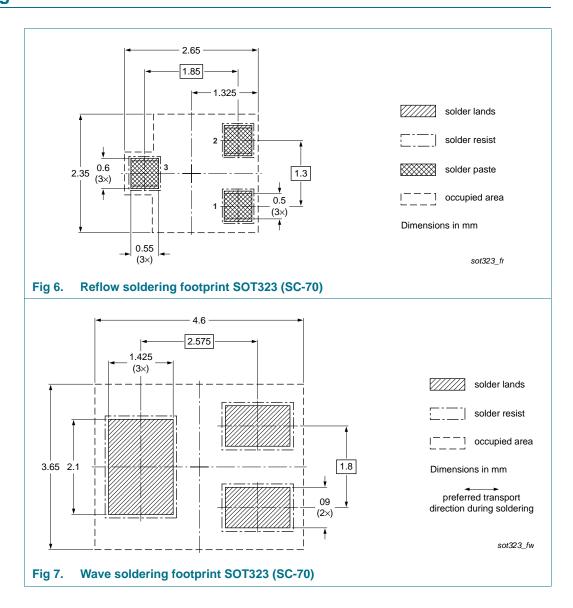
Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description Packing		quantity	
			3000	10000	
BAT54W series	SOT323	4 mm pitch, 8 mm tape and reel	-115	-135	

^[1] For further information and the availability of packing methods, see Section 14.

11. Soldering



12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BAT54W_SER v.3	20121120	Product data sheet	-	BAT54W v.2		
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of NXP Semiconductors. 					
	 Legal texts have been adapted to the new company name where appropriate. 					
	Section 1: updated					
	• Section 4: updated					
	 <u>Table 5</u>: updated ambient temperature T_{amb} maximum value to 150 °C 					
	• Figure 1 to 4: updated					
	Section 8 "Test information": added					
	• Figure 5: replaced by minimized package outline drawing					
	Section 10 "Packing information": added					
	Section 11 "Soldering": added					
	Section 13	"Legal information": updated	d			
BAT54W v.2	19960319	Product specification	-	BAT54W v.1		

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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BAT54W_SER

BAT54W series

Schottky barrier diodes

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